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April 1st, 2010
Renesas Electronics Corporation

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DATA SHEET

RENESAS

# SILICON POWER TRANSISTOR
# 2SC4552

## NPN SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SC4552 is a power transistor developed for high-speed switching and features low $V_{CE(sat)}$ and high $h_{FE}$. This transistor is ideal for use in drivers such as DC/DC converters and actuators.

In addition, a small resin-molded insulation type package contributes to high-density mounting and reduction of mounting cost.

### FEATURES

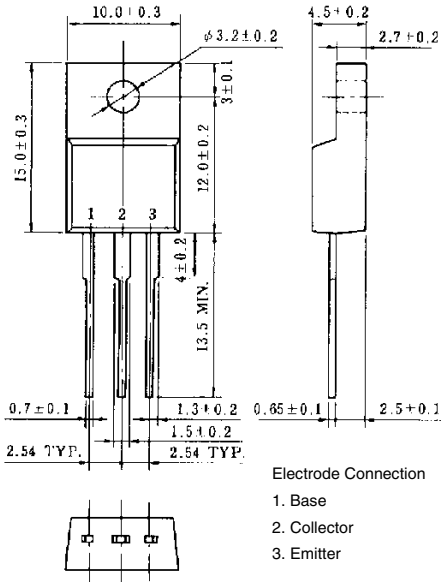
- High $h_{FE}$ and low $V_{CE(sat)}$:
  $h_{FE} \geq 100$ ($V_{CE}$ = 2 V, $I_C$ = 3 A)
  $V_{CE(sat)} \leq 0.3$ V ($I_C$ = 8 A, $I_B$ = 0.4 A)
- Mold package that does not require an insulating board or insulation bushing

### ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

| Parameter | Symbol | Ratings | Unit |
|---|---|---|---|
| Collector to base voltage | $V_{CBO}$ | 100 | V |
| Collector to emitter voltage | $V_{CEO}$ | 60 | V |
| Emitter to base voltage | $V_{EBO}$ | 7.0 | V |
| Collector current (DC) | $I_{C(DC)}$ | 15 | A |
| Collector current (pulse) | $I_{C(pulse)}$* | 30 | A |
| Base current (DC) | $I_{B(DC)}$ | 7.5 | A |
| Total power dissipation | $P_T$ ($T_C$ = 25°C) | 30 | W |
| Total power dissipation | $P_T$ ($T_a$ = 25°C) | 2.0 | W |
| Junction temperature | $T_j$ | 150 | °C |
| Storage temperature | $T_{stg}$ | –55 to +150 | °C |

* PW ≤ 300 μs, duty cycle ≤ 10%

### PACKAGE DRAWING (UNIT: mm)




Electrode Connection
1. Base
2. Collector
3. Emitter



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Printed in Japan

## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

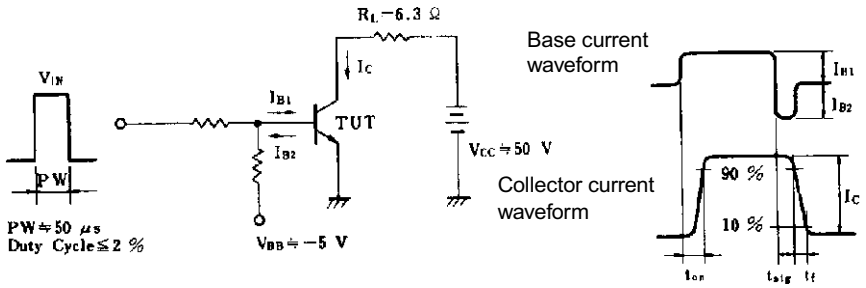
| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|---|---|---|---|---|---|
| Collector to emitter voltage | $V_{CEO(SUS)}$ | $I_C$ = 8.0 A, $I_B$ = 0.8 A, L = 1 mH | 60 | | | V |
| Collector to emitter voltage | $V_{CEX(SUS)}$ | $I_C$ = 8.0 A, $I_{B1}$ = $-I_{B2}$ = 0.8 A, $V_{BE(OFF)}$ = −1.5 V, L = 180 μH, clamped | 60 | | | V |
| Collector cutoff current | $I_{CBO}$ | $V_{CB}$ = 60 V, $I_E$ = 0 | | | 10 | μA |
| Collector cutoff current | $I_{CER}$ | $V_{CE}$ = 60 V, $R_{BE}$ = 50 Ω, Ta = 125°C | | | 1.0 | mA |
| Collector cutoff current | $I_{CEX1}$ | $V_{CE}$ = 60 V, $V_{BE(OFF)}$ = −1.5 V | | | 10 | μA |
| Collector cutoff current | $I_{CEX2}$ | $V_{CE}$ = 60 V, $V_{BE(OFF)}$ = −1.5 V, Ta = 125°C | | | 1.0 | mA |
| Emitter cutoff current | $I_{EBO}$ | $V_{EB}$ = 5.0 V, $I_C$ = 0 | | | 10 | μA |
| DC current gain | $h_{FE1}$* | $V_{CE}$ = 2.0 V, $I_C$ = 1.5 A | 100 | | | |
| DC current gain | $h_{FE2}$* | $V_{CE}$ = 2.0 V, $I_C$ = 3.0 A | 100 | | 400 | |
| DC current gain | $h_{FE3}$* | $V_{CE}$ = 2.0 V, $I_C$ = 8.0 A | 60 | | | |
| Collector saturation voltage | $V_{CE(sat)1}$* | $I_C$ = 8.0 A, $I_B$ = 0.4 A | | | 0.3 | V |
| Collector saturation voltage | $V_{CE(sat)2}$* | $I_C$ = 12 A, $I_B$ = 0.6 A | | | 0.5 | V |
| Base saturation voltage | $V_{BE(sat)1}$* | $I_C$ = 8.0 A, $I_B$ = 0.4 A | | | 1.2 | V |
| Base saturation voltage | $V_{BE(sat)2}$* | $I_C$ = 12 A, $I_B$ = 0.6 A | | | 1.5 | V |
| Collector capacitance | $C_{ob}$ | $V_{CB}$ = 10 V, $I_E$ = 0, f = 1.0 MHz | | 180 | | pF |
| Gain bandwidth product | $f_T$ | $V_{CE}$ = 10 V, $I_C$ = 1.5 A | | 120 | | MHz |
| Turn-on time | $t_{on}$ | $I_C$ = 8.0 A, $R_L$ = 6.3 Ω, $I_{B1}$ = $-I_{B2}$ = 0.4 A, $V_{CC}$ ≅ 50 V Refer to the test circuit. | | | 0.3 | μs |
| Storage time | $t_{stg}$ | | | | 1.5 | μs |
| Fall time | $t_f$ | | | | 0.3 | μs |

* Pulse test PW ≤ 350 μs, duty cycle ≤ 2%

## $h_{FE}$ CLASSIFICATION

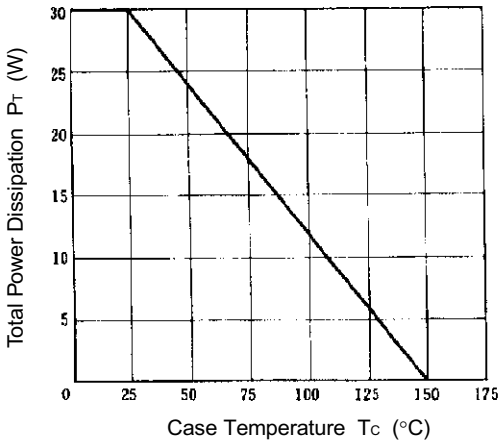
| Marking | M | L | K |
|---|---|---|---|
| $h_{FE2}$ | 100 to 200 | 150 to 300 | 200 to 400 |

## SWITCHING TIME ($t_{on}$, $t_{stg}$, $t_f$) TEST CIRCUIT

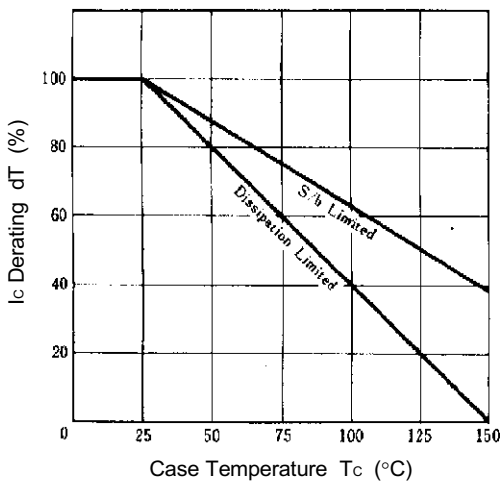


## TYPICAL CHARACTERISTICS (Ta = 25°C)

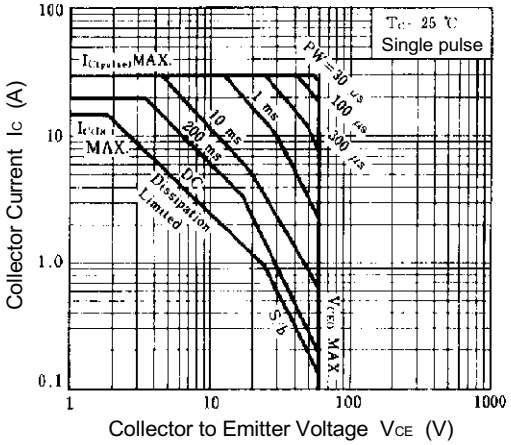
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



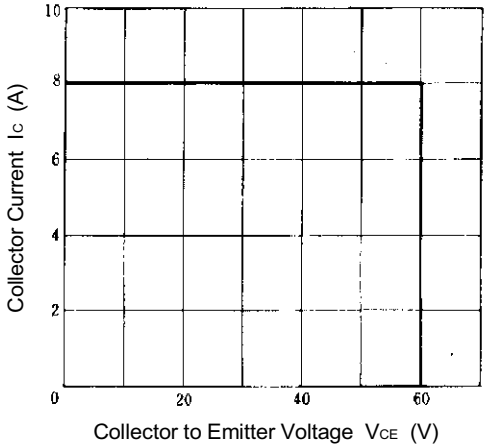

DERATING CURVE OF SAFE OPERATING AREA



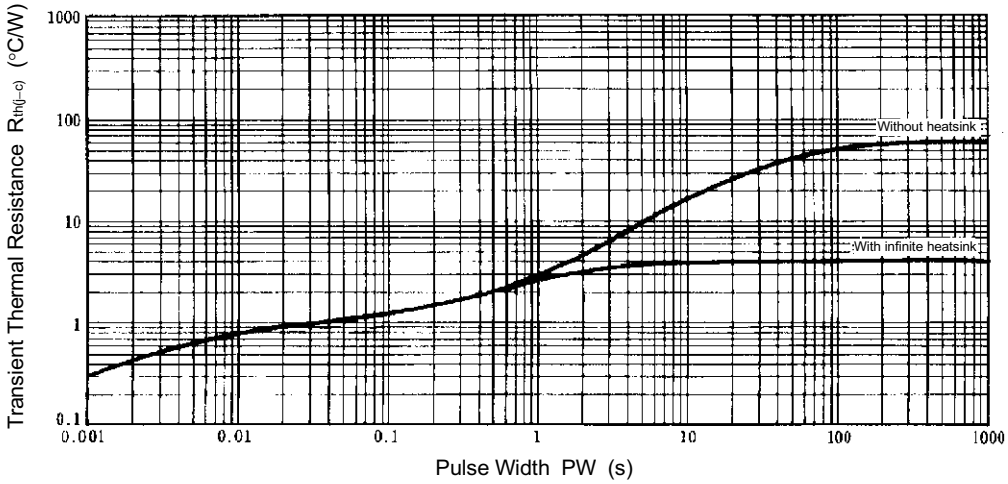

FORWARD BIAS SAFE OPERATING AREA



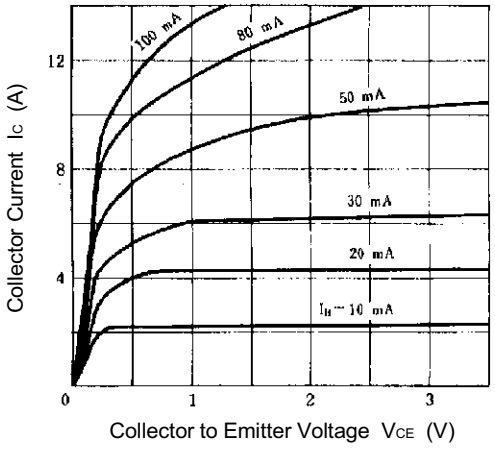

REVERSE BIAS SAFE OPERATING AREA



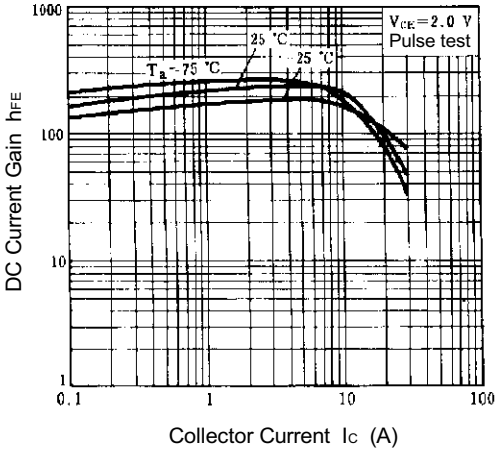

TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



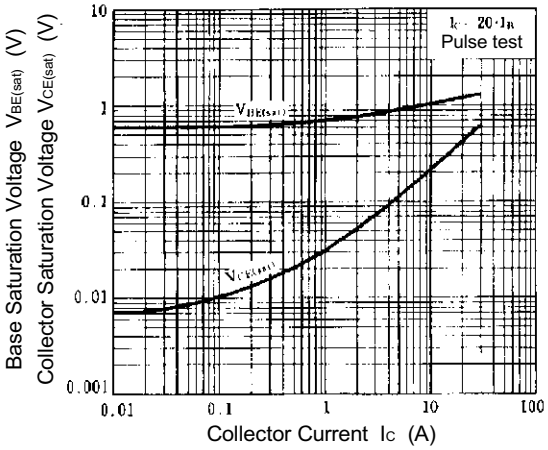
COLLECTOR CURRENT vs.
COLLECTOR TO EMITTER VOLTAGE



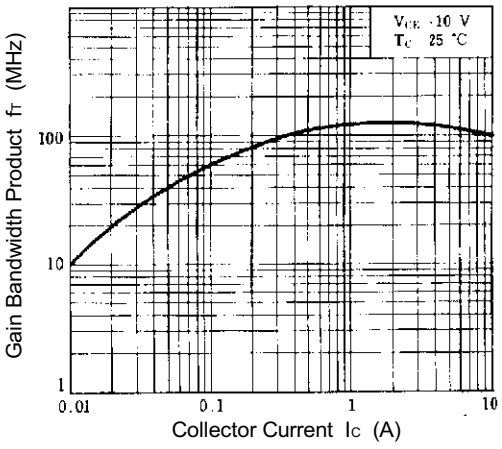

DC CURRENT GAIN vs. COLLECTOR CURRENT



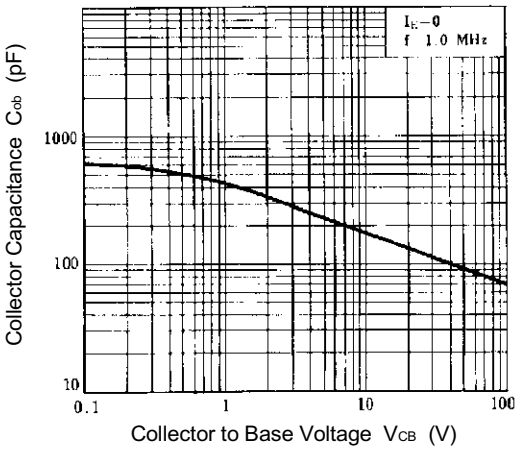

COLLECTOR AND BASE SATURATION VOLTAGE
vs. COLLECTOR CURRENT



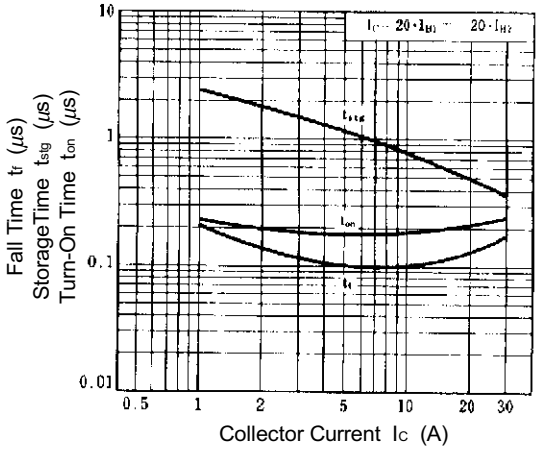

GAIN BANDWIDTH PRODUCT vs.
COLLECTOR CURRENT




OUTPUT CAPACITANCE vs.
COLLECTOR TO BASE VOLTAGE




TURN ON TIME, STORAGE TIME AND FALL TIME
vs. COLLECTOR CURRENT



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